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Details	
Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	516096
Number of I/O	620
Number of Gates	3000000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 125°C (TJ)
Package / Case	896-BGA
Supplier Device Package	896-FBGA (31x31)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3pe3000l-fg896m

Table 2-28 • Summary of Maximum and Minimum DC Input Levels Applicable to Military Conditions

	Military[1]	
	I_{IL}[2]	I_{IH}[3]
DC I/O Standard	**µA**	**µA**
3.3 V LVTTL / 3.3 V LVCMOS	15	15
3.3 V LVCMOS Wide Range	15	15
2.5 V LVCMOS	15	15
1.8 V LVCMOS	15	15
1.5 V LVCMOS	15	15
1.2 V LVCMOS[4]	15	15
1.2 V LVCMOS Wide Range[4]	15	15
3.3 V PCI	15	15
3.3 V PCI-X	15	15
3.3 V GTL	15	15
2.5 V GTL	15	15
3.3 V GTL+	15	15
2.5 V GTL+	15	15
HSTL (I)	15	15
HSTL (II)	15	15
SSTL2 (I)	15	15
SSTL2 (II)	15	15
SSTL3 (I)	15	15
SSTL3 (II)	15	15

Notes:

1. *Military temperature range: –55°C to 125°C.*
2. *I_{IL} is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
3. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.*
4. *Applicable to Military A3PE600L and A3PE3000L devices operating at VCCI ≥ VCC.*

Table 2-38 • I/O Output Buffer Maximum Resistances [1]
Applicable to Standard Plus I/O Banks for A3P250 and A3P1000 Only

Standard	Drive Strength	$R_{PULL\text{-}DOWN}$ (Ω) [2]	$R_{PULL\text{-}UP}$ (Ω) [3]
3.3 V LVTTL / 3.3 V LVCMOS	2 mA	100	300
	4 mA	100	300
	6 mA	50	150
	8 mA	50	150
	12 mA	25	75
	16 mA	25	75
3.3 V LVCMOS Wide Range	100 µA	Same as regular 3.3 V LVCMOS	
2.5 V LVCMOS	2 mA	100	200
	4 mA	100	200
	6 mA	50	100
	8 mA	50	100
	12 mA	25	50
1.8 V LVCMOS	2 mA	200	225
	4 mA	100	112
	6 mA	50	56
	8 mA	50	56
1.5 V LVCMOS	2 mA	200	224
	4 mA	100	112
3.3 V PCI/PCI-X	Per PCI/PCI-X specification	25	75

Notes:

1. *These maximum values are provided for informational reasons only. Minimum output buffer resistance values depend on V_{CCI}, drive strength selection, temperature, and process. For board design considerations and detailed output buffer resistances, use the corresponding IBIS models located at http://www.microsemi.com/products/fpga-soc/design-resources/ibis-models.*
2. $R_{(PULL\text{-}DOWN\text{-}MAX)} = (VOLspec) / IOLs_{pec}$
3. $R_{(PULL\text{-}UP\text{-}MAX)} = (VCCImax – VOHspec) / I_{OHspec}$

Table 2-39 • I/O Weak Pull-Up/Pull-Down Resistances
Minimum and Maximum Weak Pull-Up/Pull-Down Resistance Values

VCCI	$R_{(WEAK\ PULL\text{-}UP)}$ (Ω) [1]		$R_{(WEAK\ PULL\text{-}DOWN)}$ (Ω) [2]	
	Min.	Max.	Min.	Max.
3.3 V	10 k	95 k	13 k	45 k
3.3 V (wide range I/Os)	10 k	95 k	13 k	45 k
2.5 V	11 k	100 k	17 k	74 k
1.8 V	19 k	85 k	23 k	110 k
1.5 V	20 k	120 k	17 k	156 k
1.2 V	30 k	450 k	25 k	300 k
1.2 V (wide range I/Os)	20 k	450 k	17 k	300 k

Notes:

1. $R_{(WEAK\ PULL\text{-}UP\text{-}MAX)} = (VCCImax – VOHspec) / I_{(WEAK\ PULL\text{-}UP\text{-}MIN)}$
2. $R_{(WEAK\ PULL\text{-}DOWN\text{-}MAX)} = (VOLspec) / I_{(WEAK\ PULL\text{-}UP\text{-}MIN)}$

2.5 V LVCMOS

Low-Voltage CMOS for 2.5 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 2.5 V applications.

Table 2-70 • Minimum and Maximum DC Input and Output Levels Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

2.5 V LVCMOS	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL} [1]	I_{IH} [2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA [3]	Max. mA [3]	µA [4]	µA [4]
4 mA	–0.3	0.7	1.7	3.6	0.7	1.7	4	4	16	18	15	15
8 mA	–0.3	0.7	1.7	3.6	0.7	1.7	8	8	32	37	15	15
12 mA	–0.3	0.7	1.7	3.6	0.7	1.7	12	12	65	74	15	15
16 mA	–0.3	0.7	1.7	3.6	0.7	1.7	16	16	83	87	15	15
24 mA	–0.3	0.7	1.7	3.6	0.7	1.7	24	24	169	124	15	15

Notes:

1. *I_{IL} is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges*
3. *Currents are measured at 100°C junction temperature and maximum voltage.*
4. *Currents are measured at 125°C junction temperature.*
5. *Software default selection highlighted in gray.*

Table 2-71 • Minimum and Maximum DC Input and Output Levels Applicable to Advanced I/O Banks

2.5 V LVCMOS	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL} [1]	I_{IH} [2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA [3]	Max. mA [3]	µA [4]	µA [4]
2 mA	–0.3	0.7	1.7	2.7	0.7	1.7	2	2	16	18	15	15
4 mA	–0.3	0.7	1.7	2.7	0.7	1.7	4	4	16	18	15	15
6 mA	–0.3	0.7	1.7	2.7	0.7	1.7	6	6	32	37	15	15
8 mA	–0.3	0.7	1.7	2.7	0.7	1.7	8	8	32	37	15	15
12 mA	–0.3	0.7	1.7	2.7	0.7	1.7	12	12	65	74	15	15
16 mA	–0.3	0.7	1.7	2.7	0.7	1.7	16	16	83	87	15	15
24 mA	–0.3	0.7	1.7	2.7	0.7	1.7	24	24	169	124	15	15

Notes:

1. *I_{IL} is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges*
3. *Currents are measured at 100°C junction temperature and maximum voltage.*
4. *Currents are measured at 125°C junction temperature.*
5. *Software default selection highlighted in gray.*

1.8 V LVCMOS

Low-voltage CMOS for 1.8 V is an extension of the LVCMOS standard (JESD8-5) used for general-purpose 1.8 V applications. It uses a 1.8 V input buffer and a push-pull output buffer.

Table 2-82 • Minimum and Maximum DC Input and Output Levels Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

1.8 V LVCMOS	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL}[1]	I_{IH}[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
2 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	2	2	9	11	15	15
4 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	4	4	17	22	15	15
6 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	6	6	35	44	15	15
8 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	8	8	45	51	15	15
12 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	12	12	91	74	15	15
16 mA	–0.3	0.35 * VCCI	0.65 * VCCI	3.6	0.45	VCCI – 0.45	16	16	91	74	15	15

Notes:

1. *I_{IL} is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges*
3. *Currents are measured at 100°C junction temperature and maximum voltage.*
4. *Currents are measured at 125°C junction temperature.*
5. *Software default selection highlighted in gray.*

Table 2-83 • Minimum and Maximum DC Input and Output Levels Applicable to Advanced I/O Banks

1.8 V LVCMOS	VIL		VIH		VOL	V_{OH}	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL}[1]	I_{IH}[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
2 mA	–0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI – 0.45	2	2	9	11	15	15
4 mA	–0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI – 0.45	4	4	17	22	15	15
6 mA	–0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI – 0.45	6	6	35	44	15	15
8 mA	–0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI – 0.45	8	8	45	51	15	15
12 mA	–0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI – 0.45	12	12	91	74	15	15
16 mA	–0.3	0.35 * VCCI	0.65 * VCCI	1.9	0.45	VCCI – 0.45	16	16	91	74	15	15

Notes:

1. *I_{IL} is the input leakage current per I/O pin over recommended operation conditions where –0.3 V < VIN < VIL.*
2. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges*
3. *Currents are measured at 100°C junction temperature and maximum voltage.*
4. *Currents are measured at 125°C junction temperature.*
5. *Software default selection highlighted in gray.*

1.5 V DC Core Voltage

Table 2-100 • 1.5 V LVCMOS Low Slew
Military-Case Conditions: T_J = 125°C, VCC = 1.425 V, Worst-Case VCCI = 1.4 V
Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	Std.	0.61	9.39	0.04	1.88	2.77	0.40	9.54	7.77	3.22	2.47	11.00	9.24	ns
	–1	0.52	7.99	0.03	1.60	2.35	0.34	8.11	6.61	2.74	2.10	9.36	7.86	ns
4 mA	Std.	0.61	8.01	0.04	1.88	2.77	0.40	8.13	6.77	3.58	3.14	9.59	8.24	ns
	–1	0.52	6.81	0.03	1.60	2.35	0.34	6.91	5.76	3.05	2.67	8.16	7.01	ns
6 mA	Std.	0.61	7.51	0.04	1.88	2.77	0.40	7.62	6.59	3.66	3.32	9.09	8.05	ns
	–1	0.52	6.39	0.03	1.60	2.35	0.34	6.48	5.60	3.12	2.83	7.73	6.85	ns
8 mA	Std.	0.61	7.41	0.04	1.88	2.77	0.40	7.52	6.59	3.41	3.99	8.99	8.06	ns
	–1	0.52	6.30	0.03	1.60	2.35	0.34	6.40	5.61	2.90	3.40	7.64	6.85	ns
12 mA	Std.	0.61	7.41	0.04	1.88	2.77	0.40	7.52	6.59	3.41	3.99	8.99	8.06	ns
	–1	0.52	6.30	0.03	1.60	2.35	0.34	6.40	5.61	2.90	3.40	7.64	6.85	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-101 • 1.5 V LVCMOS High Slew
Military-Case Conditions: T_J = 125°C, VCC = 1.425 V, Worst-Case VCCI = 1.4 V
Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{PYS}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	Std.	0.61	3.78	0.04	1.88	2.77	0.40	3.82	3.43	3.21‘	2.58	5.29	4.89	ns
	–1	0.52	3.21	0.03	1.60	2.35	0.34	3.25	2.92	2.73	2.20	4.50	4.16	ns
4 mA	Std.	0.61	3.20	0.04	1.88	2.77	0.40	3.23	2.79	3.57	3.25	4.70	4.25	ns
	–1	0.52	2.72	0.03	1.60	2.35	0.34	2.75	2.37	3.04	2.77	4.00	3.62	ns
6 mA	Std.	0.61	3.09	0.04	1.88	2.77	0.40	3.12	2.67	3.65	3.44	4.59	4.13	ns
	–1	0.52	2.63	0.03	1.60	2.35	0.34	2.65	2.27	3.11	2.93	3.90	3.52	ns
8 mA	Std.	0.61	3.05	0.04	1.88	2.77	0.40	3.09	2.52	3.77	4.14	4.55	3.98	ns
	–1	0.52	2.60	0.03	1.60	2.35	0.34	2.62	2.14	3.21	3.52	3.87	3.39	ns
12 mA	Std.	0.61	3.05	0.04	1.88	2.77	0.40	3.09	2.52	3.77	4.14	4.55	3.98	ns
	–1	0.52	2.60	0.03	1.60	2.35	0.34	2.62	2.14	3.21	3.52	3.87	3.39	ns

Notes:

1. *Software default selection highlighted in gray.*
2. *For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.*

2.5 V GTL

Gunning Transceiver Logic is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The V_{CCI} pin should be connected to 2.5 V.

Table 2-124 • Minimum and Maximum DC Input and Output Levels

2.5 V GTL	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL}[1]	I_{IH}[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
20 mA[5]	–0.3	VREF – 0.05	VREF + 0.05	3.6	0.4	–	20	20	169	124	15	15

Notes:

1. *I_{IL} is the input leakage current per I/O pin over recommended operating conditions where –0.3 V < VIN < VIL.*
2. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.*
3. *Currents are measured at 100°C junction temperature and maximum voltage.*
4. *Currents are measured at 125°C junction temperature.*
5. *Output drive strength is below JEDEC specification.*

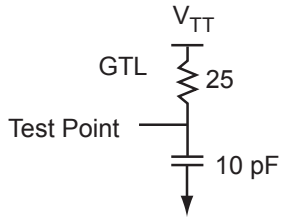


Figure 2-16 • AC Loading

Table 2-125 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	V_{TT} (typ.) (V)	C_{LOAD} (pF)
VREF – 0.05	VREF + 0.05	0.8	0.8	1.2	10

*Note: *Measuring point = V_{trip}. See Table 2-29 on page 2-25 for a complete table of trip points.*

Timing Characteristics

Table 2-126 • 2.5 V GTL
Military-Case Conditions: T_J = 125°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI = 3.0 V, VREF = 0.8 V
Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.80	2.11	0.05	2.26	0.52	2.14	2.11	–	–	4.34	4.31	ns
–1	0.68	1.79	0.05	1.93	0.44	1.82	1.79	–	–	3.70	3.68	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-127 • 2.5 V GTL
Military-Case Conditions: T_J = 125°C, VCC = 1.425 V,
Worst-Case VCCI = 3.0 V, VREF = 0.8 V
Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.61	2.02	0.04	2.04	0.40	1.98	2.02	–	–	3.45	3.49	ns
–1	0.52	1.72	0.03	1.73	0.34	1.69	1.72	–	–	2.93	2.97	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

3.3 V GTL+

Gunning Transceiver Logic Plus is a high-speed bus standard (JESD8-3). It provides a differential amplifier input buffer and an open-drain output buffer. The VCCI pin should be connected to 3.3 V.

Table 2-128 • Minimum and Maximum DC Input and Output Levels

3.3 V GTL+	VIL		VIH		VOL	VOH	I_{OL}	I_{OH}	I_{OSL}	I_{OSH}	I_{IL}[1]	I_{IH}[2]
Drive Strength	Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA	Max. mA[3]	Max. mA[3]	µA[4]	µA[4]
35 mA	–0.3	VREF – 0.1	VREF + 0.1	3.6	0.6	–	35	35	268	181	15	15

Notes:

1. *I_{IL} is the input leakage current per I/O pin over recommended operating conditions where –0.3 V < VIN < VIL.*
2. *I_{IH} is the input leakage current per I/O pin over recommended operating conditions VIH < VIN < VCCI. Input current is larger when operating outside recommended ranges.*
3. *Currents are measured at 100°C junction temperature and maximum voltage.*
4. *Currents are measured at 125°C junction temperature.*

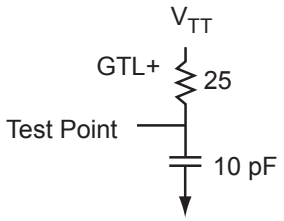


Figure 2-17 • AC Loading

Table 2-129 • AC Waveforms, Measuring Points, and Capacitive Loads

Input Low (V)	Input High (V)	Measuring Point* (V)	VREF (typ.) (V)	VTT (typ.) (V)	C_{LOAD} (pF)
VREF – 0.1	VREF + 0.1	1.0	1.0	1.5	10

*Note: *Measuring point = V_{trip}. See Table 2-29 on page 2-25 for a complete table of trip points.*

Timing Characteristics

Table 2-130 • 3.3 V GTL+
Military-Case Conditions: T_J = 125°C, Worst-Case VCC = 1.14 V,
Worst-Case VCCI = 3.0 V, VREF = 1.0 V
Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.80	2.04	0.05	2.34	0.52	2.07	2.03	–	–	4.28	4.24	ns
–1	0.68	1.74	0.05	1.99	0.44	1.76	1.73	–	–	3.64	3.61	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

Table 2-131 • 3.3 V GTL+
Military-Case Conditions: T_J = 125°C, VCC = 1.425 V,
Worst-Case VCCI = 3.0 V, VREF = 1.0 V
Applicable to Pro I/Os for A3PE600L and A3PE3000L Only

Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
Std.	0.61	1.95	0.04	2.11	0.40	1.92	1.95	–	–	3.38	3.41	ns
–1	0.52	1.66	0.03	1.79	0.34	1.63	1.66	–	–	2.88	2.90	ns

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

LVPECL

Low-Voltage Positive Emitter-Coupled Logic (LVPECL) is another differential I/O standard. It requires that one data bit be carried through two signal lines. Like LVDS, two pins are needed. It also requires external resistor termination.

The full implementation of the LVDS transmitter and receiver is shown in an example in Figure 2-27. The building blocks of the LVPECL transmitter-receiver are one transmitter macro, one receiver macro, three board resistors at the transmitter end, and one resistor at the receiver end. The values for the three driver resistors are different from those used in the LVDS implementation because the output standard specifications are different.

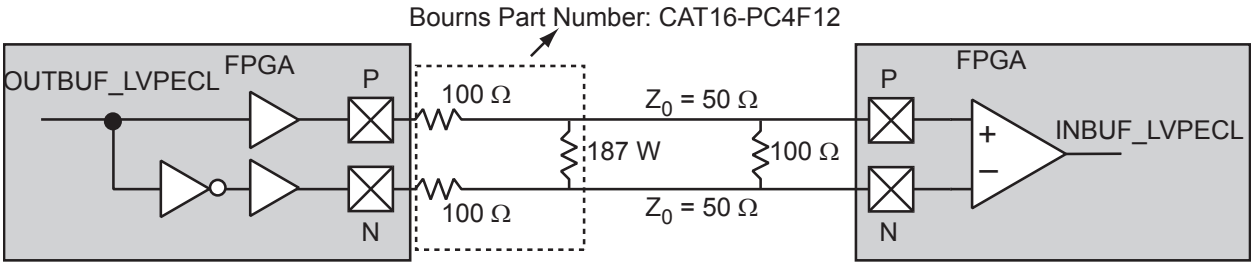


Figure 2-27 • **LVPECL Circuit Diagram and Board-Level Implementation**

Table 2-165 • **Minimum and Maximum DC Input and Output Levels**

DC Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Units
VCCI	Supply Voltage	3.0		3.3		3.6		V
VOL	Output Low Voltage	0.96	1.27	1.06	1.43	1.30	1.57	V
VOH	Output High Voltage	1.8	2.11	1.92	2.28	2.13	2.41	V
VIL, VIH	Input Low, Input High Voltages	0	3.3	0	3.6	0	3.9	V
V_{ODIFF}	Differential Output Voltage	0.625	0.97	0.625	0.97	0.625	0.97	V
V_{OCM}	Output Common-Mode Voltage	1.762	1.98	1.762	1.98	1.762	1.98	V
V_{ICM}	Input Common-Mode Voltage	1.01	2.57	1.01	2.57	1.01	2.57	V
V_{IDIFF}	Input Differential Voltage	300		300		300		mV

Table 2-166 • **AC Waveforms, Measuring Points, and Capacitive Loads**

Input Low (V)	Input High (V)	Measuring Point* (V)
1.64	1.94	Cross point

*Note: *Measuring point = V_{trip}. See Table 2-29 on page 2-25 for a complete table of trip points.*

Output Register

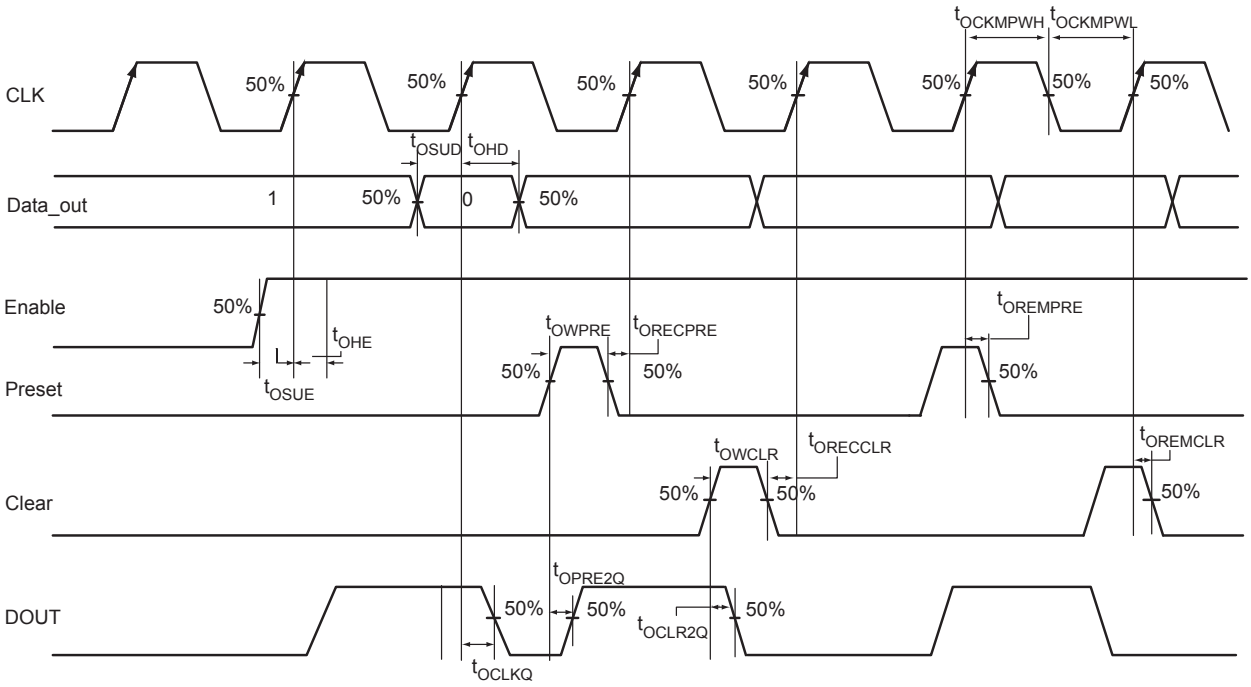


Figure 2-31 • **Output Register Timing Diagram**

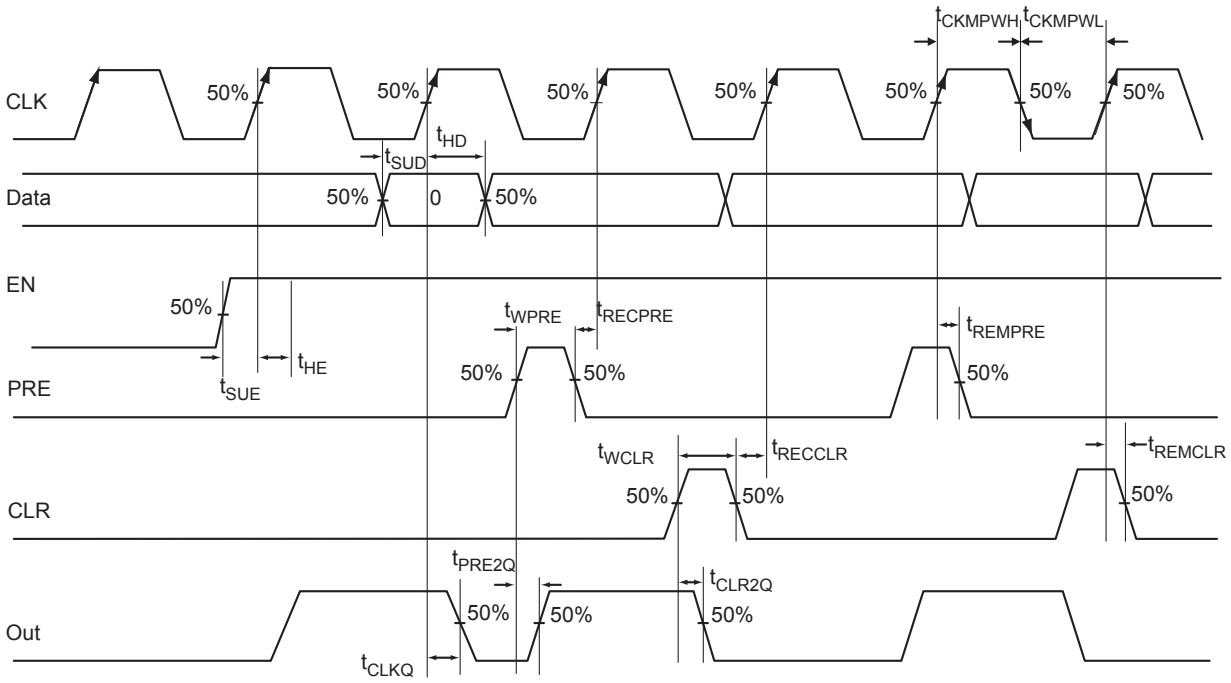


Figure 2-40 • **Timing Model and Waveforms**

Global Resource Characteristics

A3P1000 Clock Tree Topology

Clock delays are device-specific. Figure 2-41 is an example of a global tree used for clock routing. The global tree presented in Figure 2-41 is driven by a CCC located on the west side of the A3P1000 device. It is used to drive all D-flip-flops in the device.

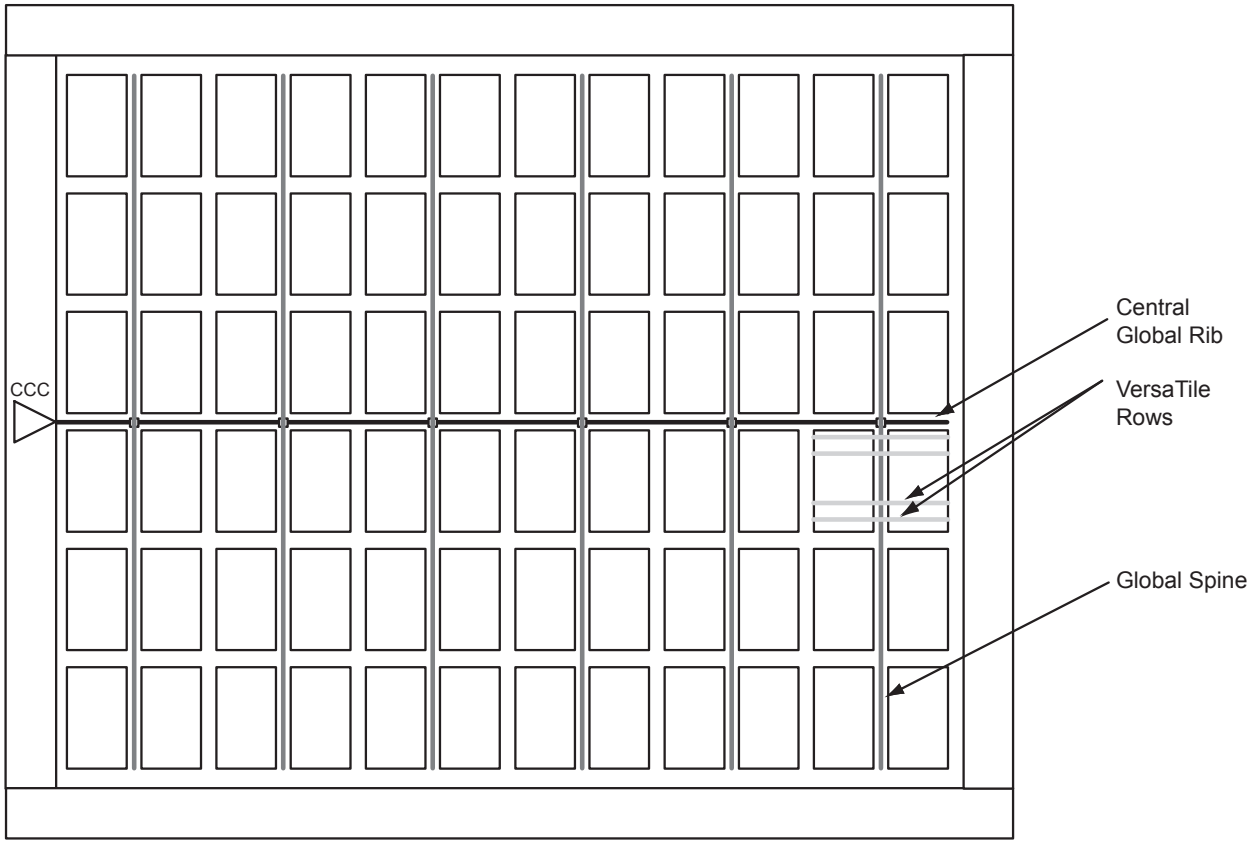


***Figure 2-41* • Example of Global Tree Use in an A3P1000 Device for Clock Routing**

Table 2-199 • A3P250 Global Resource
Military-Case Conditions: T_J = 125°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	0.97	1.24	1.14	1.46	ns
t_{RCKH}	Input High Delay for Global Clock	0.94	1.27	1.11	1.49	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock					ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock					ns
t_{RCKSW}	Maximum Skew for Global Clock		0.32		0.38	ns
F_{RMAX}	Maximum Frequency for Global Clock					MHz

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.*

Table 2-200 • A3P1000 Global Resource
Military-Case Conditions: T_J = 125°C, VCC = 1.425 V

Parameter	Description	–1		Std.		Units
		Min.[1]	Max.[2]	Min.[1]	Max.[2]	
t_{RCKL}	Input Low Delay for Global Clock	1.18	1.44	1.39	1.70	ns
t_{RCKH}	Input High Delay for Global Clock	1.17	1.48	1.37	1.74	ns
$t_{RCKMPWH}$	Minimum Pulse Width High for Global Clock					ns
$t_{RCKMPWL}$	Minimum Pulse Width Low for Global Clock					ns
t_{RCKSW}	Maximum Skew for Global Clock		0.32		0.37	ns
F_{RMAX}	Maximum Frequency for Global Clock					MHz

Notes:

1. *Value reflects minimum load. The delay is measured from the CCC output to the clock pin of a sequential element, located in a lightly loaded row (single element is connected to the global net).*
2. *Value reflects maximum load. The delay is measured on the clock pin of the farthest sequential element, located in a fully loaded row (all available flip-flops are connected to the global net in the row).*
3. *For specific junction temperature and voltage supply levels, refer to Table 2-7 on page 2-6 for derating values.*

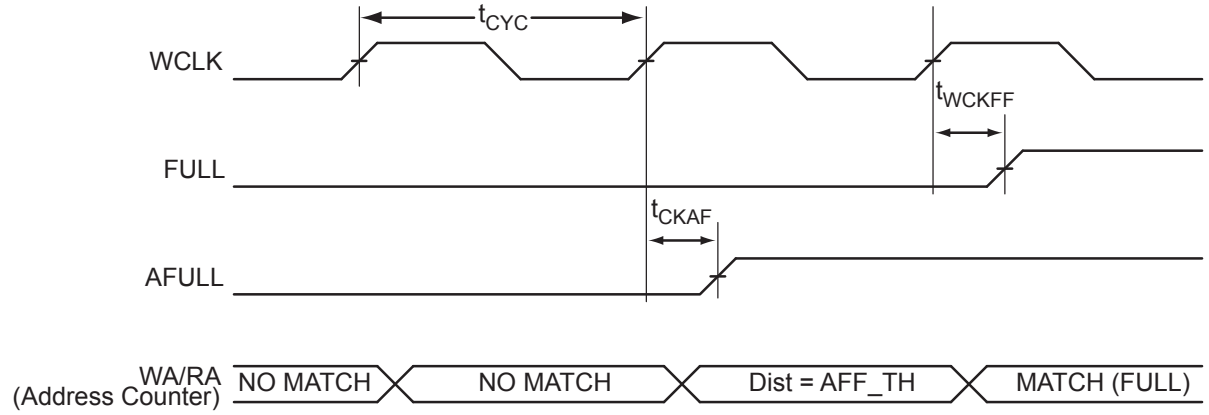


Figure 2-52 • **FIFO FULL Flag and AFULL Flag Assertion**

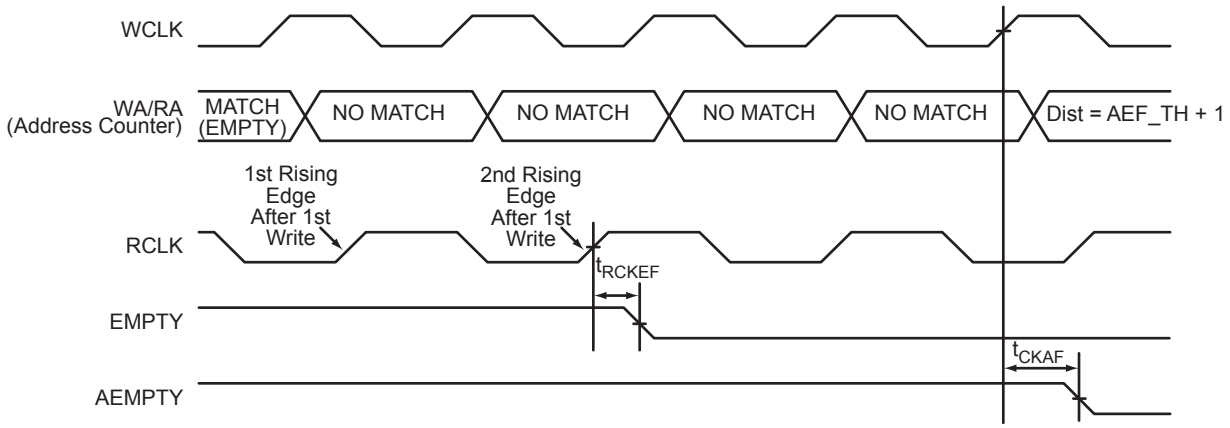


Figure 2-53 • **FIFO EMPTY Flag and AEMPTY Flag Deassertion**

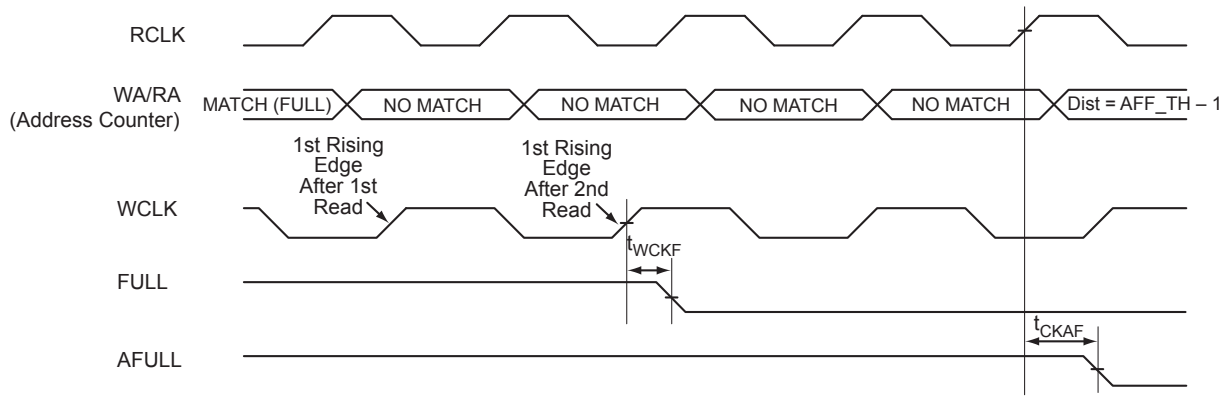


Figure 2-54 • **FIFO FULL Flag and AFULL Flag Deassertion**

Timing Characteristics

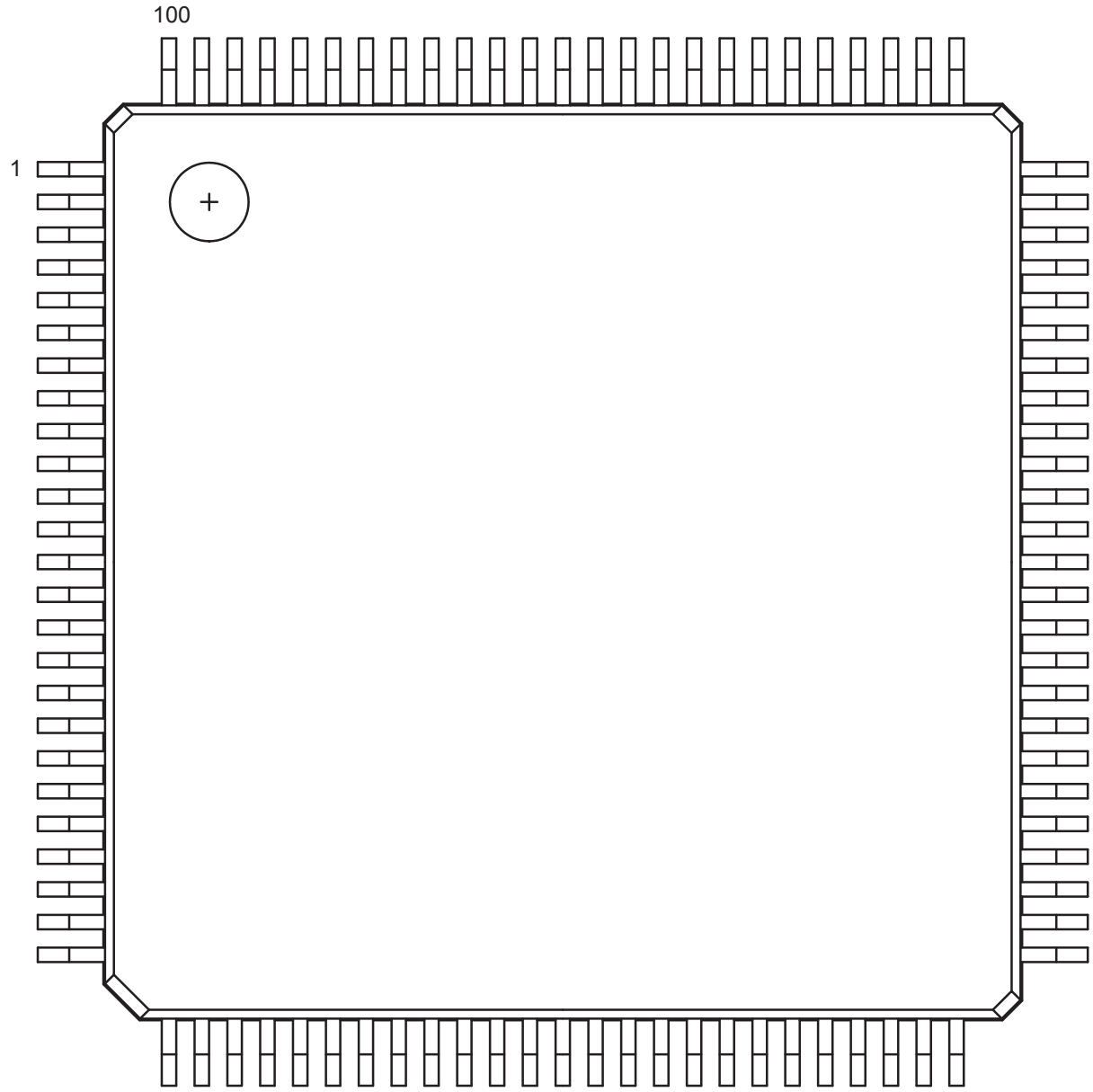
Table 2-209 • FIFO Worst Military-Case Conditions: T_J = 125°C, VCC = 1.14 V for A3PE600L and A3PE3000L

Parameter	Description	–1	Std.	Units
t_{ENS}	REN, WEN Setup Time	1.91	2.24	ns
t_{ENH}	REN, WEN Hold Time	0.03	0.03	ns
t_{BKS}	BLK Setup Time	0.40	0.47	ns
t_{BKH}	BLK Hold Time	0.00	0.00	ns
t_{DS}	Input Data (WD) Setup Time	0.25	0.30	ns
t_{DH}	Input Data (WD) Hold Time	0.00	0.00	ns
t_{CKQ1}	Clock HIGH to New Data Valid on RD (flow-through)	3.26	3.84	ns
t_{CKQ2}	Clock HIGH to New Data Valid on RD (pipelined)	1.24	1.46	ns
t_{RCKEF}	RCLK HIGH to Empty Flag Valid	2.38	2.80	ns
t_{WCKFF}	WCLK HIGH to Full Flag Valid	2.26	2.66	ns
t_{CKAF}	Clock HIGH to Almost Empty/Full Flag Valid	8.57	10.08	ns
t_{RSTFG}	RESET LOW to Empty/Full Flag Valid	2.34	2.76	ns
t_{RSTAF}	RESET LOW to Almost Empty/Full Flag Valid	8.48	9.97	ns
t_{RSTBQ}	RESET LOW to Data Out LOW on RD (flow-through)	1.28	1.50	ns
	RESET LOW to Data Out LOW on RD (pipelined)	1.28	1.50	ns
$t_{REMRSTB}$	RESET Removal	0.40	0.47	ns
$t_{RECRSTB}$	RESET Recovery	2.08	2.44	ns
$t_{MPWRSTB}$	RESET Minimum Pulse Width	0.66	0.76	ns
t_{CYC}	Clock Cycle Time	6.08	6.99	ns
F_{MAX}	Maximum Frequency for FIFO	164	143	MHz

Note: For specific junction temperature and voltage supply levels, refer to Table 2-6 on page 2-6 for derating values.

4 – Package Pin Assignments

VQ100



Note: This is the top view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at http://www.microsemi.com/products/fpga-soc/solutions.

FG484	
Pin Number	A3P1000 Function
K13	GND
K14	VCC
K15	VCCIB1
K16	GCC1/IO91PPB1
K17	IO90NPB1
K18	IO88PDB1
K19	IO88NDB1
K20	IO94NPB1
K21	IO98NDB1
K22	IO98PDB1
L1	NC
L2	IO200PDB3
L3	IO210NPB3
L4	GFB0/IO208NPB3
L5	GFA0/IO207NDB3
L6	GFB1/IO208PPB3
L7	VCOMPLF
L8	GFC0/IO209NPB3
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	VCC
L15	GCC0/IO91NPB1
L16	GCB1/IO92PPB1
L17	GCA0/IO93NPB1
L18	IO96NPB1
L19	GCB0/IO92NPB1
L20	IO97PDB1
L21	IO97NDB1
L22	IO99NPB1
M1	NC
M2	IO200NDB3
M3	IO206NDB3

FG484	
Pin Number	A3P1000 Function
M4	GFA2/IO206PDB3
M5	GFA1/IO207PDB3
M6	VCCPLF
M7	IO205NDB3
M8	GFB2/IO205PDB3
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	VCC
M15	GCB2/IO95PPB1
M16	GCA1/IO93PPB1
M17	GCC2/IO96PPB1
M18	IO100PPB1
M19	GCA2/IO94PPB1
M20	IO101PPB1
M21	IO99PPB1
M22	NC
N1	IO201NDB3
N2	IO201PDB3
N3	NC
N4	GFC2/IO204PDB3
N5	IO204NDB3
N6	IO203NDB3
N7	IO203PDB3
N8	VCCIB3
N9	VCC
N10	GND
N11	GND
N12	GND
N13	GND
N14	VCC
N15	VCCIB1
N16	IO95NPB1

FG484	
Pin Number	A3P1000 Function
N17	IO100NPB1
N18	IO102NDB1
N19	IO102PDB1
N20	NC
N21	IO101NPB1
N22	IO103PDB1
P1	NC
P2	IO199PDB3
P3	IO199NDB3
P4	IO202NDB3
P5	IO202PDB3
P6	IO196PPB3
P7	IO193PPB3
P8	VCCIB3
P9	GND
P10	VCC
P11	VCC
P12	VCC
P13	VCC
P14	GND
P15	VCCIB1
P16	GDB0/IO112NPB1
P17	IO106NDB1
P18	IO106PDB1
P19	IO107PDB1
P20	NC
P21	IO104PDB1
P22	IO103NDB1
R1	NC
R2	IO197PPB3
R3	VCC
R4	IO197NPB3
R5	IO196NPB3
R6	IO193NPB3
R7	GEC0/IO190NPB3

FG484	
Pin Number	A3P1000 Function
Y3	NC
Y4	IO182RSB2
Y5	GND
Y6	IO177RSB2
Y7	IO174RSB2
Y8	VCC
Y9	VCC
Y10	IO154RSB2
Y11	IO148RSB2
Y12	IO140RSB2
Y13	NC
Y14	VCC
Y15	VCC
Y16	NC
Y17	NC
Y18	GND
Y19	NC
Y20	NC
Y21	NC
Y22	VCCIB1
AA1	GND
AA2	VCCIB3
AA3	NC
AA4	IO181RSB2
AA5	IO178RSB2
AA6	IO175RSB2
AA7	IO169RSB2
AA8	IO166RSB2
AA9	IO160RSB2
AA10	IO152RSB2
AA11	IO146RSB2
AA12	IO139RSB2
AA13	IO133RSB2
AA14	NC
AA15	NC

FG484	
Pin Number	A3P1000 Function
AA16	IO122RSB2
AA17	IO119RSB2
AA18	IO117RSB2
AA19	NC
AA20	NC
AA21	VCCIB1
AA22	GND
AB1	GND
AB2	GND
AB3	VCCIB2
AB4	IO180RSB2
AB5	IO176RSB2
AB6	IO173RSB2
AB7	IO167RSB2
AB8	IO162RSB2
AB9	IO156RSB2
AB10	IO150RSB2
AB11	IO145RSB2
AB12	IO144RSB2
AB13	IO132RSB2
AB14	IO127RSB2
AB15	IO126RSB2
AB16	IO123RSB2
AB17	IO121RSB2
AB18	IO118RSB2
AB19	NC
AB20	VCCIB2
AB21	GND
AB22	GND

FG484	
Pin Number	A3PE3000L Function
H13	VCCIB1
H14	VCCIB1
H15	VMV1
H16	GBC2/IO84PDB2V0
H17	IO83NDB2V0
H18	IO100NDB2V2
H19	IO100PDB2V2
H20	VCC
H21	VMV2
H22	IO105PDB2V2
J1	IO285NDB7V1
J2	IO285PDB7V1
J3	VMV7
J4	IO279PDB7V0
J5	IO283PDB7V1
J6	IO281PDB7V0
J7	IO287NDB7V1
J8	VCCIB7
J9	GND
J10	VCC
J11	VCC
J12	VCC
J13	VCC
J14	GND
J15	VCCIB2
J16	IO84NDB2V0
J17	IO104NDB2V2
J18	IO104PDB2V2
J19	IO106PPB2V3
J20	GNDQ
J21	IO109PDB2V3
J22	IO107PDB2V3
K1	IO277NDB7V0
K2	IO277PDB7V0
K3	GNDQ

FG484	
Pin Number	A3PE3000L Function
K4	IO279NDB7V0
K5	IO283NDB7V1
K6	IO281NDB7V0
K7	GFC1/IO275PPB7V0
K8	VCCIB7
K9	VCC
K10	GND
K11	GND
K12	GND
K13	GND
K14	VCC
K15	VCCIB2
K16	GCC1/IO112PPB2V3
K17	IO108NDB2V3
K18	IO108PDB2V3
K19	IO110NPB2V3
K20	IO106NPB2V3
K21	IO109NDB2V3
K22	IO107NDB2V3
L1	IO257PSB6V2
L2	IO276PDB7V0
L3	IO276NDB7V0
L4	GFB0/IO274NPB7V0
L5	GFA0/IO273NDB6V4
L6	GFB1/IO274PPB7V0
L7	VCOMPLF
L8	GFC0/IO275NPB7V0
L9	VCC
L10	GND
L11	GND
L12	GND
L13	GND
L14	VCC
L15	GCC0/IO112NPB2V3
L16	GCB1/IO113PPB2V3

FG484	
Pin Number	A3PE3000L Function
L17	GCA0/IO114NPB3V0
L18	VCOMPLC
L19	GCB0/IO113NPB2V3
L20	IO110PPB2V3
L21	IO111NDB2V3
L22	IO111PDB2V3
M1	GNDQ
M2	IO255NPB6V2
M3	IO272NDB6V4
M4	GFA2/IO272PDB6V4
M5	GFA1/IO273PDB6V4
M6	VCCPLF
M7	IO271NDB6V4
M8	GFB2/IO271PDB6V4
M9	VCC
M10	GND
M11	GND
M12	GND
M13	GND
M14	VCC
M15	GCB2/IO116PPB3V0
M16	GCA1/IO114PPB3V0
M17	GCC2/IO117PPB3V0
M18	VCCPLC
M19	GCA2/IO115PDB3V0
M20	IO115NDB3V0
M21	IO126PDB3V1
M22	IO124PSB3V1
N1	IO255PPB6V2
N2	IO253NDB6V2
N3	VMV6
N4	GFC2/IO270PPB6V4
N5	IO261PPB6V3
N6	IO263PDB6V3
N7	IO263NDB6V3

FG896	
Pin Number	**A3PE3000L Function**
H26	IO84NDB2V0
H27	IO96PDB2V1
H28	IO96NDB2V1
H29	IO89PDB2V0
H30	IO89NDB2V0
J1	IO290NDB7V2
J2	IO290PDB7V2
J3	IO302NDB7V3
J4	IO302PDB7V3
J5	IO295NDB7V2
J6	IO299NDB7V3
J7	VCCIB7
J8	VCCPLA
J9	VCC
J10	IO04NPB0V0
J11	IO18NDB0V2
J12	IO20NDB0V2
J13	IO20PDB0V2
J14	IO32NDB0V3
J15	IO32PDB0V3
J16	IO42PDB1V0
J17	IO44NDB1V0
J18	IO44PDB1V0
J19	IO54NDB1V1
J20	IO54PDB1V1
J21	IO76NPB1V4
J22	VCC
J23	VCCPLB
J24	VCCIB2
J25	IO90PDB2V1
J26	IO90NDB2V1
J27	GBB2/IO83PDB2V0
J28	IO83NDB2V0
J29	IO91PDB2V1
J30	IO91NDB2V1
K1	IO288NDB7V1

Revision	Changes	Page
Revision 1 (June 2011)	In the "High Performance" section, 66-Bit PCI was corrected to 64-Bit PCI (SAR 31977).	I
	The A3P250 device and VQ100 package were added to product tables in the "Military ProASIC3/EL Low Power Flash FPGAs" chapter (SAR 30526).	I
	The Y security option and Licensed DPA Logo were added to the "Military ProASIC3/EL Ordering Information" section. The trademarked Licensed DPA Logo identifies that a product is covered by a DPA counter-measures license from Cryptography Research (SAR 32151).	III
	The A3P250 device was added to applicable tables in the "Military ProASIC3/EL DC and Switching Characteristics" chapter (SAR 30526).	2-1
	The VPUMP voltage for operation mode was changed from "0 to 3.45 V" to "0 to 3.6 V" in Table 2-2 • Recommended Operating Conditions [1](SAR 25220).	2-2
	3.3 V LVCMOS wide range and 1.2 V LVCMOS wide range were added to applicable tables in the following sections (SAR 28061): Table 2-2 • Recommended Operating Conditions [1] "Power per I/O Pin" "Overview of I/O Performance" "Summary of I/O Timing Characteristics – Default I/O Software Settings" "User I/O Characteristics" "Detailed I/O DC Characteristics" "Single-Ended I/O Characteristics" (SAR 31925)	 2-2 2-9 2-22 2-25 2-18 2-29 2-37